

Fast Recovery Diodes (Stud Version), 6 A, 12 A



DO-203AA (DO-4)

FEATURES

- Short reverse recovery time
- Low stored charge
- Wide current range
- Excellent surge capabilities
- Standard JEDEC® types
- Stud cathode and stud anode versions
- Fully characterized reverse recovery conditions
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

- DC power supplies
- Inverters
- Converters
- Choppers
- Ultrasonic systems
- Freewheeling diodes

PRODUCT SUMMARY

$I_{F(AV)}$	6 A, 12 A
Package	DO-203AA (DO-4)
Circuit configuration	Single diode

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	TEST CONDITIONS	1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	UNITS
$I_{F(AV)}$		6 ⁽¹⁾	12 ⁽¹⁾	A
	T_C maximum	100	100	°C
$I_{F(RMS)}$		9.5	19	A
I_{FSM}	50 Hz	72	145	A
	60 Hz	75 ⁽¹⁾	150 ⁽¹⁾	
I^2t	50 Hz	26	103	A ² s
	60 Hz	23	94	
$I^2\sqrt{t}$		363	856	$I^2\sqrt{s}$
V_{RRM}	Range	50 to 400 ⁽¹⁾	50 to 400 ⁽¹⁾	V
t_{rr}		See Recovery Characteristics table	See Recovery Characteristics table	ns
T_J	Range	-65 to +150	-65 to +150	°C

Note

⁽¹⁾ JEDEC® registered values



ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 25 °C μA	I _{RRM} MAXIMUM AT T _J = 100 °C mA	I _{RRM} MAXIMUM AT T _J = 150 °C mA
1N3879(R)	-	50	75	15 ⁽¹⁾	1.0 ⁽¹⁾	3.0 ⁽¹⁾
1N3880(R)		100	150			
1N3881(R)		200	250			
1N3882(R)		300	350			
1N3883(R)		400	450			
1N3889(R)	-	50	75	25 ⁽¹⁾	3.0 ⁽¹⁾	5.0 ⁽¹⁾
1N3890(R)		100	150			
1N3891(R)		200	250			
1N3892(R)		300	350			
1N3893(R)		400	450			

Note

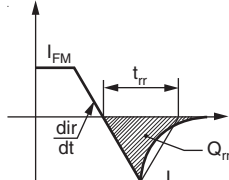
(1) JEDEC® registered values

FORWARD CONDUCTION								
PARAMETER	SYMBOL	TEST CONDITIONS			1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave DC			6 ⁽¹⁾	12 ⁽¹⁾	A	
					100	100	°C	
Maximum RMS current	I _{F(RMS)}				9.5	19	A	
Maximum peak, one-cycle non-repetitive forward current	I _{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T _J = 150 °C	85	170		
		t = 8.3 ms			90	180		
		t = 10 ms	100 % V _{RRM} reapplied		72	145		
		t = 8.3 ms			75 ⁽¹⁾	150 ⁽¹⁾		
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied		36	145	A ² s	
		t = 8.3 ms			33	130		
		t = 10 ms	100 % V _{RRM} reapplied		26	103		
		t = 8.3 ms			23	94		
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied			363	1452	A ² √s	
Maximum forward voltage drop	V _{FM}	T _J = 25 °C; I _F = Rated I _{F(AV)} (DC)			1.4 ⁽¹⁾	1.4 ⁽¹⁾	V	
		T _C = 100 °C; I _{FM} = π x rated I _{F(AV)}			1.5 ⁽¹⁾	1.5 ⁽¹⁾		

Note

(1) JEDEC® registered values

**RECOVERY CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDITIONS	1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	UNITS	
Maximum reverse recovery time	t _{rr}	T _J = 25 °C, I _F = 1 A to V _R = 30 V, di _F /dt = 100 A/μs	150	150	ns	
		T _J = 25 °C, di _F /dt = 25 A/μs, I _{FM} = π x rated I _{F(AV)}	300 ⁽¹⁾	300 ⁽¹⁾		
Maximum peak recovery current	I _{RM(REC)}	I _{FM} = π x rated I _{F(AV)}	4 ⁽¹⁾	5 ⁽¹⁾	-	
Maximum reverse recovery charge	Q _{rr}	T _J = 25 °C, I _F = 1 A to V _R = 30 V, di _F /dt = 100 A/μs	400	350	nC	
		T _J = 25 °C, di _F /dt = 25 A/μs, I _{FM} = π x rated I _{F(AV)}	400	400		

Note⁽¹⁾ JEDEC® registered values**THERMAL AND MECHANICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	UNITS
Maximum junction operating temperature range	T _J		-65 to +150		°C
Maximum storage temperature range	T _{Stg}		-65 to +175		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	2.0	°C/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.5		
Allowable mounting torque		Not lubricated threads	1.5 + 0 - 10 % (13)		N · m (lbf · in)
		Lubricated threads	1.2 + 0 - 10 % (10)		
Approximate weight			7		g
			0.25		oz.
Case style		JEDEC®	DO-203AA (DO-4)		

 ΔR_{thJC} CONDUCTION

CONDUCTION ANGLE	1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	1N3879(R) TO 1N3883(R)	1N3889(R) TO 1N3893(R)	TEST CONDITIONS	UNITS
	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION			
180°	0.58	0.46	0.33	0.26	T _J = 150 °C	K/W
120°	0.60	0.48	0.58	0.46		
60°	1.28	1.02	1.28	1.02		
30°	2.20	1.76	2.20	1.76		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

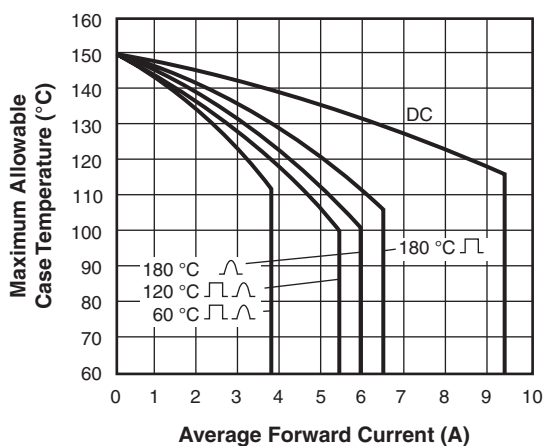


Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N3879 Series

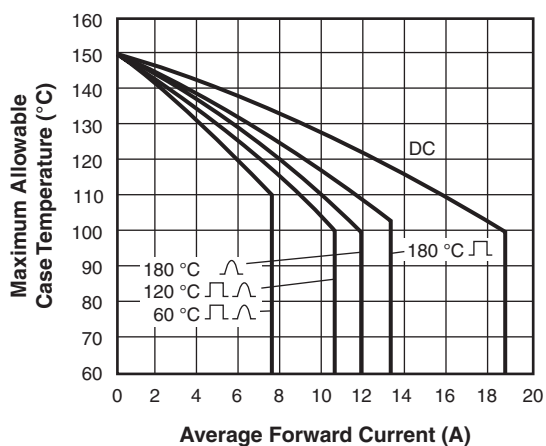
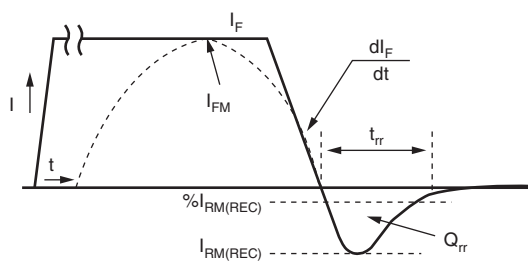


Fig. 2 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N3889 Series



I_F, I_{FM} - Peak forward current prior to commutation
 $-dI_F/dt$ - Rate of fall of forward current
 $I_{RM(REC)}$ - Peak reverse recovery current
 t_{rr} - Reverse recovery time
 Q_{rr} - Reverse recovered charge

Fig. 3 - Reverse Recovery Time Test Waveform

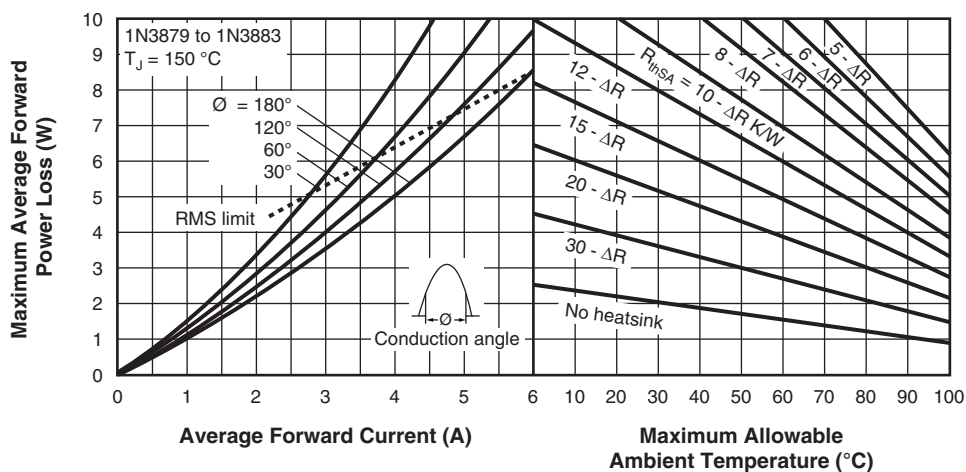


Fig. 4 - Current Rating Nomogram (Sinusoidal Waveforms), 1N3879 Series

Conduction angle - ϕ	ΔR - K/W
180°	0.58
120°	0.60
60°	1.28
30°	2.20

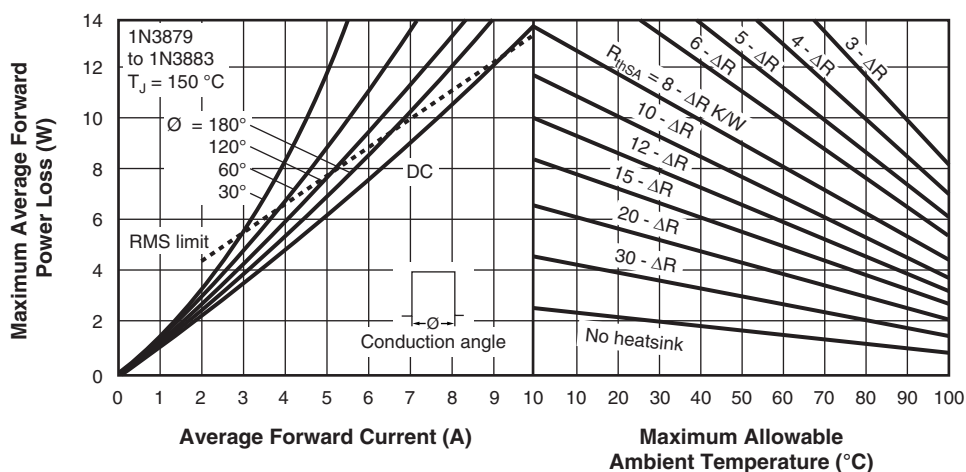


Fig. 5 - Current Rating Nomogram (Rectangular Waveforms), 1N3879 Series

Conduction angle - ϕ	$\Delta R - \text{K/W}$
DC	0
180°	0.33
120°	0.58
60°	1.28
30°	2.20

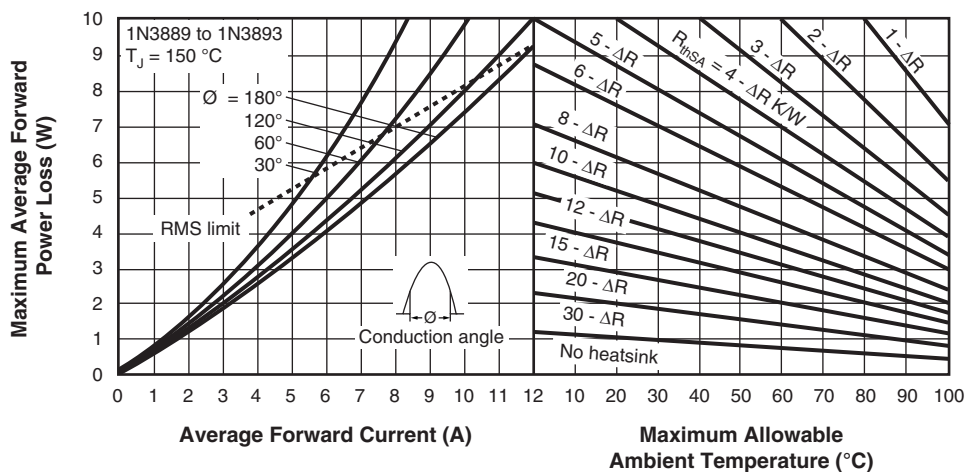


Fig. 6 - Current Rating Nomogram (Sinusoidal Waveforms), 1N3889 Series

Conduction angle - ϕ	$\Delta R - \text{K/W}$
180°	0.46
120°	0.48
60°	1.02
30°	1.76

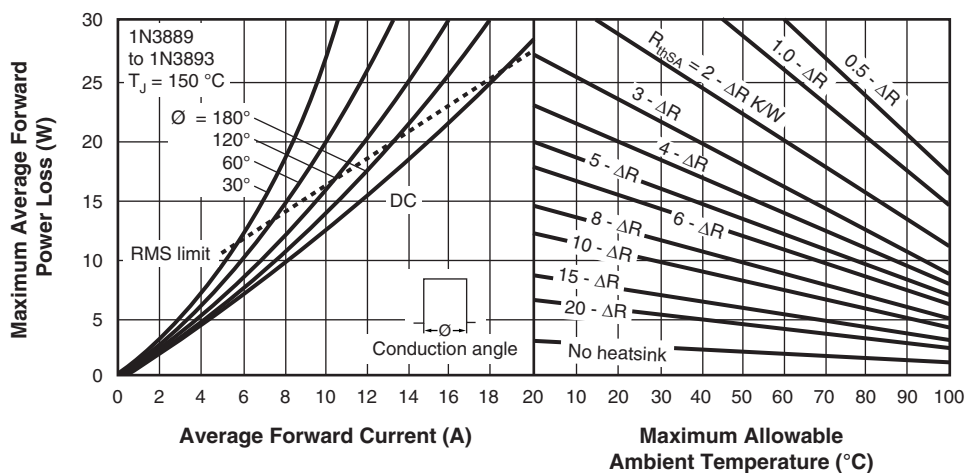


Fig. 7 - Current Rating Nomogram (Rectangular Waveforms), 1N3889 Series

Conduction angle - ϕ	$\Delta R - \text{K/W}$
DC	0
180°	0.26
120°	0.46
60°	1.02
30°	1.76

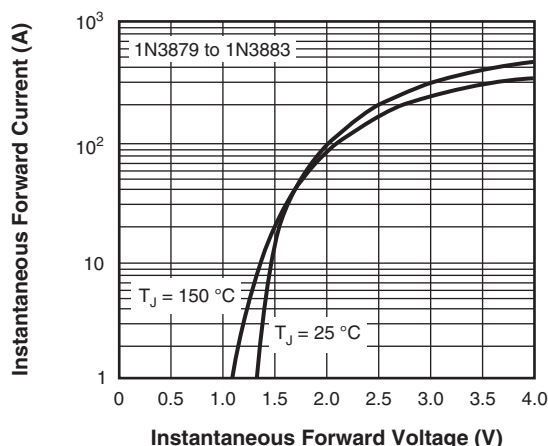


Fig. 8 - Maximum Forward Voltage vs. Forward Current, 1N3879 Series

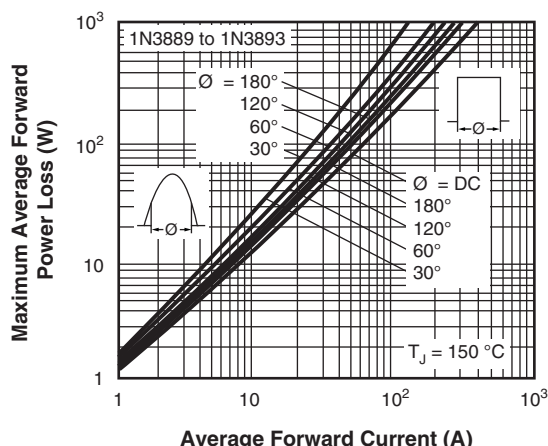


Fig. 11 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N3889 Series

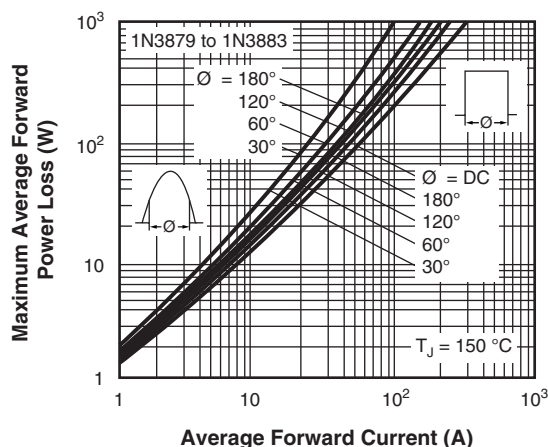


Fig. 9 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N3879 Series

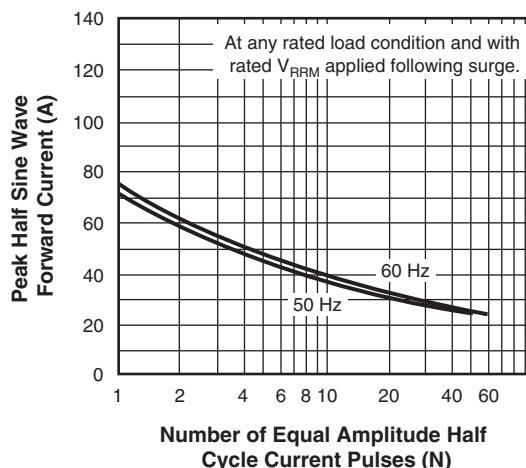


Fig. 12 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N3879 Series

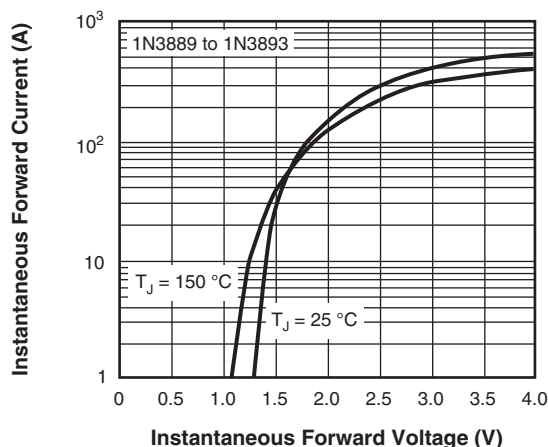


Fig. 10 - Maximum Forward Voltage vs. Forward Current, 1N3889 Series

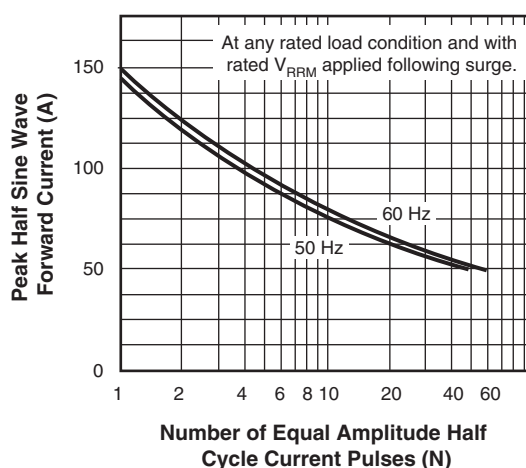


Fig. 13 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N3889 Series

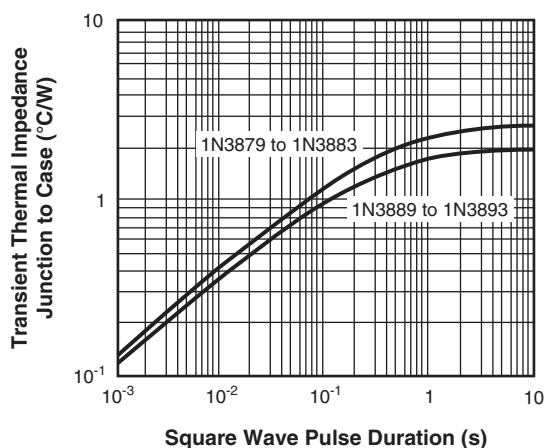
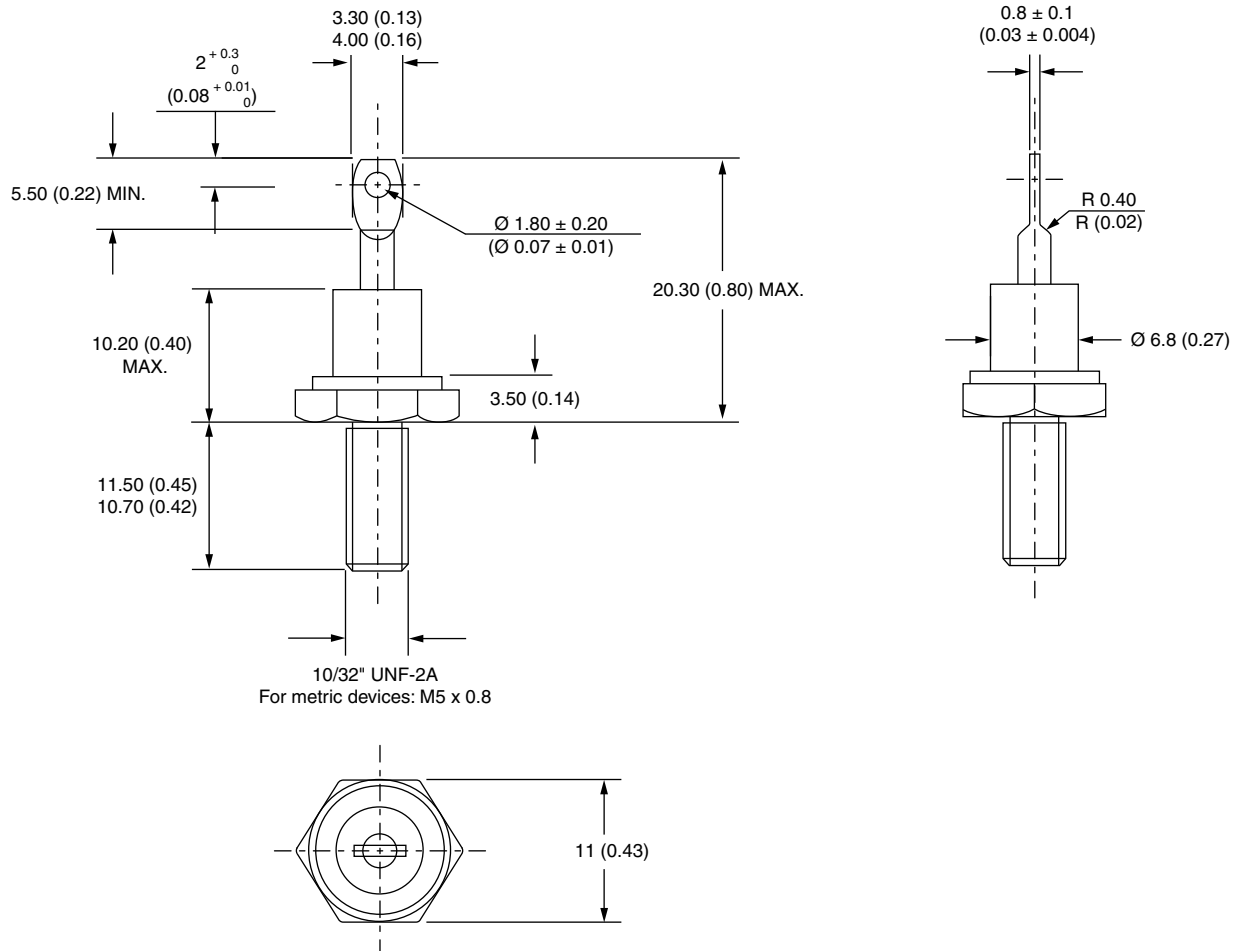


Fig. 14 - Maximum Transient Thermal Impedance, Junction to Case vs. Pulse Duration, All Series

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95311

DO-203AA (DO-4)

DIMENSIONS in millimeters (inches)





Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9